

SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

2SK4043LS—General-Purpose Switching Device **Applications**

Features

- · Low ON-resistance.
- 2.5V drive.
- · Avalanche resistance guarantee.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		30	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		20	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	80	Α
Allowable Power Dissipation	D-		2.0	W
	PD	Tc=25°C	20	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	EAS		147	mJ
Avalanche Current *2	IAV		20	Α

Note: *1 V_{DD} =10V, L=500 μH , I_{AV} =20A

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	O III
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =30V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} = ±8V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =10A	15	25		S
Static Drain-to-Source On-State Resistance	RDS(on)1	I _D =10A, V _{GS} =4V		16	21	mΩ
	RDS(on)2	ID=10A, VGS=2.5V		17	24	mΩ

Marking: K4043 Continued on next page.

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^{*2} L≤500µH, Single pulse

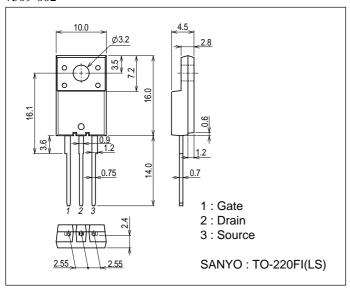
2SK4043LS

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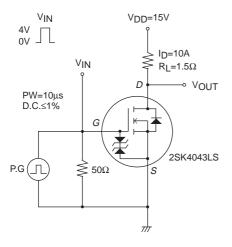
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Uill
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		3000		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		360		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		300		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit.		27		ns
Rise Time	t _r	See specified Test Circuit.		190		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		370		ns
Fall Time	tf	See specified Test Circuit.		280		ns
Total Gate Charge	Qg	V _{DS} =15V, V _{GS} =4V, I _D =20A		37		nC
Gate-to-Source Charge	Qgs	V _{DS} =15V, V _{GS} =4V, I _D =20A		3.9		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =15V, V _{GS} =4V, I _D =20A		12.6		nC
Diode Forward Voltage	V _{SD}	I _S =20A, V _{GS} =0V		1.0	1.2	V

Package Dimensions

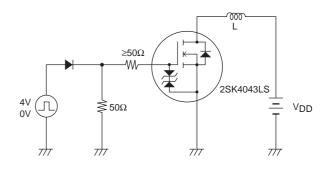
unit : mm 7509-002

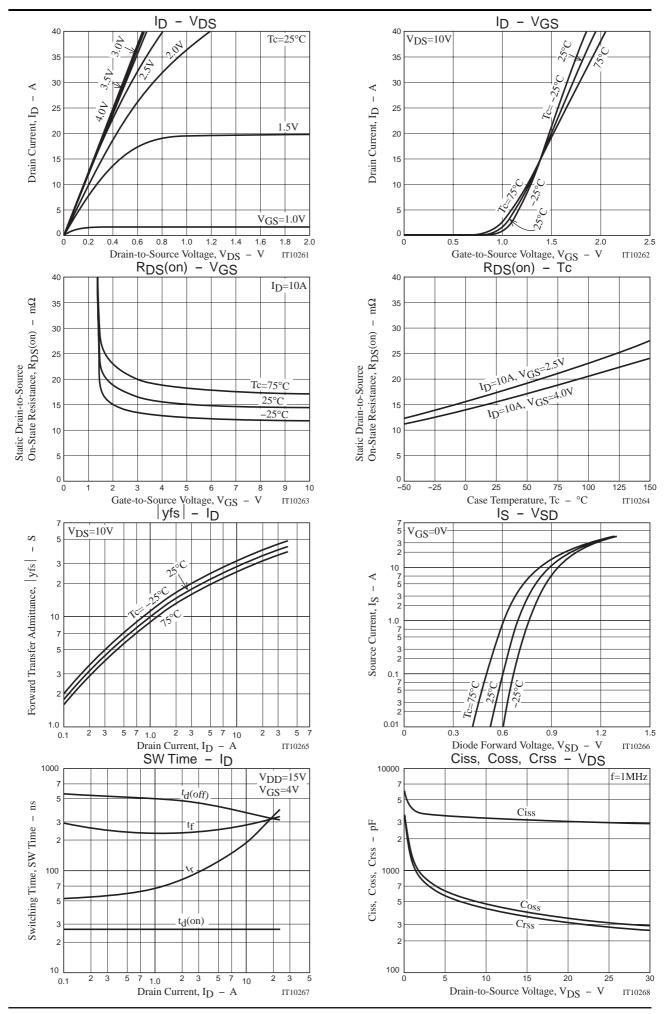


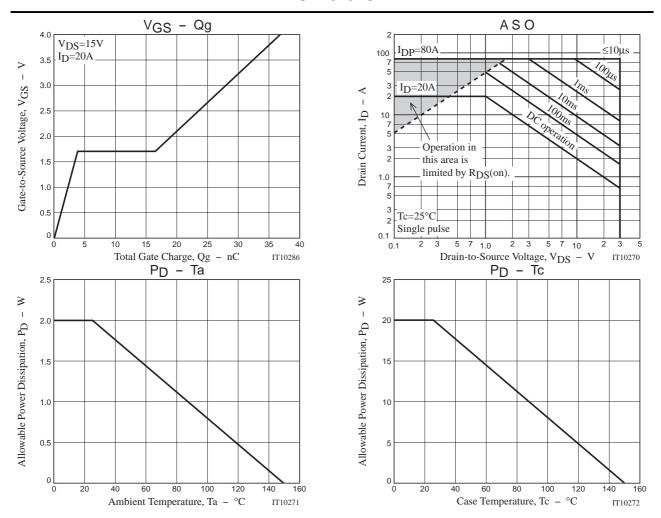
Switching Time Test Circuit



Avalanche Resistance Test Circuit







Note on usage: Since the 2SK4043LS is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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